NSN 5962-01-381-5201

Memory Microcircuit - Page 1 of 1

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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Programmable and tested to mil-std-883
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
D-9 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
2k x 8 registered prom
Voltage Rating And Type Per Characteristic:
4.5 volts applied and 5.5 volts applied
Memory Device Type:
Prom
Hybrid Technology Type:
Monolithic
Special Features:
One time programmable
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 67268-mil-bul-103
drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any
specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Fiig: